



CYPRESS

ADVANCED INFORMATION

CY27C040

## 512K x 8 CMOS EPROM

## Features

- CMOS for optimum speed/power
- High speed
  - $t_{AA} = 70$  ns max.
- Low power
  - 140 mW max.
  - Less than 550  $\mu$ W when deselected
- Byte-wide memory organization
- 100% reprogrammable in the windowed package
- EPROM technology
- Capable of withstanding >2001V static discharge
- Available in
  - 32-pin PLCC
  - 32-pin TSOP-I
  - 32-pin, 600-mil plastic or hermetic DIP
  - 32-pin hermetic LCC

## Functional Description

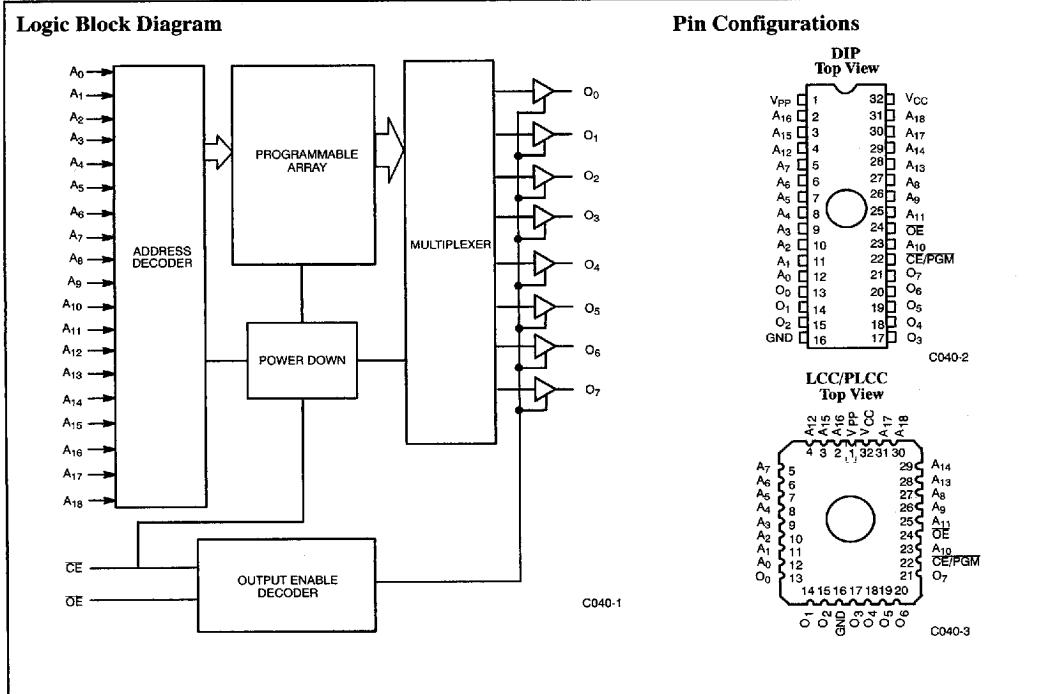
The CY27C040 is a high-performance, 4-megabit CMOS EPROM organized in 512 Kbytes. It is available in industry-standard 32-pin, 600-mil DIP, 32-pin LCC and PLCC, and 32-pin TSOP-I packages. The CY27C040 is available in windowed and opaque packages. Windowed packages allow the device to be erased with UV light for 100% reprogrammability.

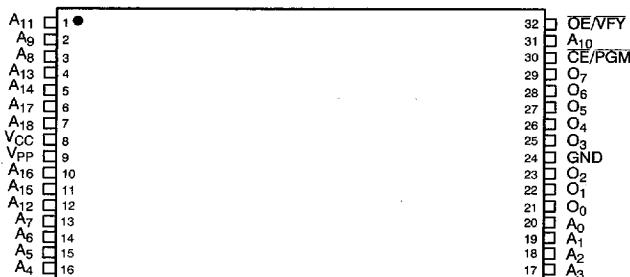
The CY27C040 is equipped with a power-down chip enable ( $\overline{CE}$ ) input and output enable ( $\overline{OE}$ ). When  $\overline{CE}$  is deasserted, the device powers down to a low-power standby mode. The  $\overline{OE}$  pin three-states the outputs without putting the device into standby mode. While  $\overline{CE}$  offers lower power,  $\overline{OE}$  provides a more rapid transition to and from three-stated outputs.

The memory cells utilize proven EPROM floating-gate technology and byte-wide intelligent programming algorithms. The EPROM cell requires only 12.75 V for the supervoltage and low programming current allows for gang programming. The device allows for each memory location to be tested 100%, because each location is written to, erased, and repeatedly exercised prior to encapsulation. Each device is also tested for AC performance to guarantee that the product will meet DC and AC specification limits after customer programming.

The CY27C040 is read by asserting both the  $\overline{CE}$  and the  $\overline{OE}$  inputs. The contents of the memory location selected by the address on inputs  $A_{18}-A_0$  will appear at the outputs  $O_7-O_0$ .

## Logic Block Diagram



**Pin Configurations (continued)**
**TSOP  
Top View**


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**Selection Guide**

		27C040-70	27C040-90	27C040-120	27C040-150	27C040-200
Maximum Access Time (ns)		70	90	120	150	200
CE Access Time (ns)		70	90	120	150	200
OE Access Time (ns)		30	35	40	50	60
I <sub>CC</sub> <sup>[1]</sup> (mA) Power Supply Current	Com'l	25	25	25	25	25
	Mil		30	30	30	30
I <sub>SB</sub> <sup>[2]</sup> (μA) CMOS Stand-by Current		100	100	100	100	100
I <sub>SB</sub> <sup>[3]</sup> (mA) TTL Stand-by Current		1	1	1	1	1

**Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... -65°C to +150°C

Ambient Temperature with

Power Applied ..... -55°C to +125°C

Supply Voltage to Ground Potential ..... -0.5V to +7.0V

DC Voltage Applied to Outputs  
in High Z State ..... -0.5V to +5.5V

DC Input Voltage ..... -3.0V to +7.0V

Transient Input Voltage ..... -3.0V for <20 ns

DC Program Voltage ..... 13.0V

UV Erasure ..... 7258 Wsec/cm<sup>2</sup>

Static Discharge Voltage ..... >2001V  
(per MIL-STD-883, Method 3015)

Latch-Up Current ..... >200 mA

**Operating Range**

Range	Ambient Temperature	V <sub>CC</sub>
Commercial	0°C to +70°C	5V ± 10%
Industrial <sup>[4]</sup>	-40°C to +85°C	5V ± 10%
Military <sup>[5]</sup>	-55°C to +125°C	5V ± 10%

4. Contact a Cypress representative for industrial temperature range specification.

5. T<sub>A</sub> is the "instant on" case temperature.

**Notes:**

1. V<sub>CC</sub> = Max., I<sub>OUT</sub> = 0 mA, f=5 MHz.
2. V<sub>CC</sub> = Max., CE = V<sub>CC</sub> - 0.3V to V<sub>CC</sub> + 1.0V.
3. V<sub>CC</sub> = Max., CE = V<sub>IH</sub>.

**Electrical Characteristics Over the Operating Range<sup>[6, 7]</sup>**

Parameter	Description	Test Conditions	Min.	Max.	Unit
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = Min., I <sub>OH</sub> = -400 µA	2.4		V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min., I <sub>OL</sub> = 2.1 mA		0.45	V
V <sub>IH</sub>	Input HIGH Level	Guaranteed Input Logical HIGH Voltage for All Inputs	2.0	V <sub>CC</sub> +0.5	V
V <sub>IL</sub>	Input LOW Level	Guaranteed Input Logical LOW Voltage for All Inputs		0.8	V
I <sub>IX</sub>	Input Leakage Current	GND ≤ V <sub>IN</sub> ≤ V <sub>CC</sub>	-10	+10	µA
I <sub>OZ</sub>	Output Leakage Current	GND ≤ V <sub>OUT</sub> ≤ V <sub>CC</sub> ; Output Disable	-10	+10	µA
I <sub>CC</sub>	Power Supply Current	V <sub>CC</sub> =Max., I <sub>OUT</sub> =0 mA, f=5 MHz	Com'l	25	mA
I <sub>SB</sub>	Stand-By Current	V <sub>CC</sub> =Max., CE = V <sub>IH</sub>	Mil	30	mA
			Com'l	1	mA
			Mil	1	mA

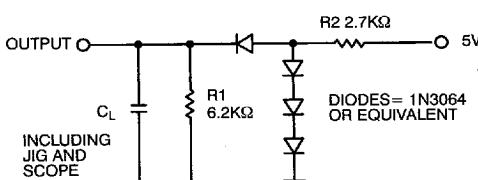
**Capacitance<sup>[7]</sup>**

Parameter	Description	Test Conditions	Max.	Unit
C <sub>IN</sub>	Input Capacitance	T <sub>A</sub> = 25°C, f = 1 MHz, V <sub>CC</sub> = 5.0V	10	pF
C <sub>OUT</sub>	Output Capacitance		10	pF

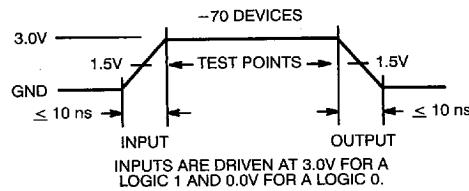
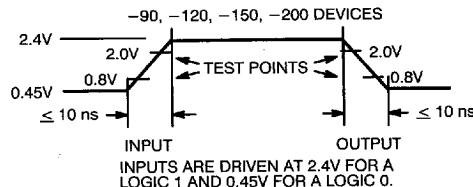
**Notes:**

6. See the last page of this specification for Group A subgroup testing information.

7. See Introduction to CMOS PROMs in this Data Book for general information on testing.

**AC Test Loads and Waveforms**


CL = 100 pF FOR -90, -120, -150, -200 DEVICES  
CL = 30 pF FOR -70 DEVICES

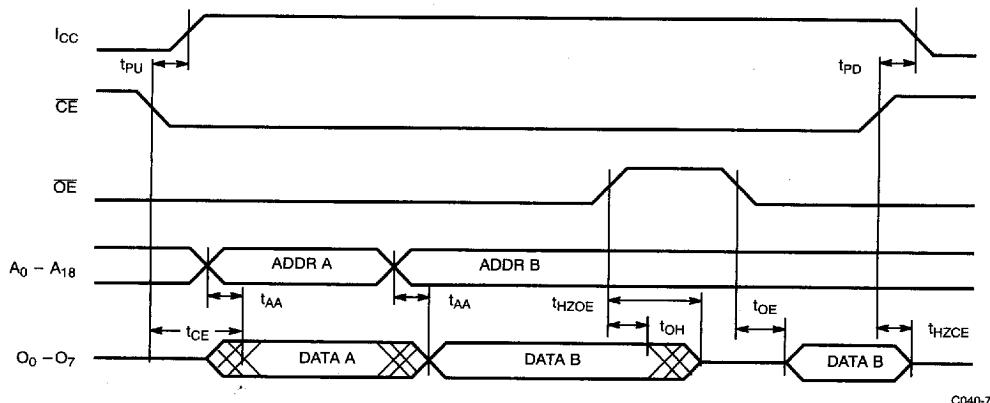


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**Switching Characteristics Over the Operating Range**

Parameter	Description	27C040-70		27C040-90		27C040-120		27C040-150		27C040-200		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
$t_{AA}$	Address to Output Valid		70		90		120		150		200	ns
$t_{OE}$	$\overline{OE}$ Active to Output Valid		30		35		40		50		60	ns
$t_{HZOE}$	$\overline{OE}$ Inactive to High Z		25		25		30		30		40	ns
$t_{CE}$	$\overline{CE}$ Active to Output Valid		70		90		120		150		200	ns
$t_{HZCE}$	$\overline{CE}$ Inactive to High Z		25		25		30		30		40	ns
$t_{PU}$	$\overline{CE}$ Active to Power-Up	0		0		0		0		0		ns
$t_{PD}$	$\overline{CE}$ Inactive to Power-Down		60		65		65		65		70	ns
$t_{OH}$	Output Data Hold	0		0		0		0		0		ns

**Switching Waveform**


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### Erasure Characteristics

Wavelengths of light less than 4000 Angstroms begin to erase the CY27C040 in the windowed package. For this reason, an opaque label should be placed over the window if the EPROM is exposed to sunlight or fluorescent lighting for extended periods of time.

The recommended dose of ultraviolet light for erasure is a wavelength of 2537 Angstroms for a minimum dose (UV intensity multiplied by exposure time) of 25 Wsec/cm<sup>2</sup>. For an ultraviolet lamp with a 12 mW/cm<sup>2</sup> power rating, the exposure time would be approximately 35 minutes. The CY27C040 needs to be within 1 inch of the lamp during erasure. Permanent damage may result if the

EPROM is exposed to high-intensity UV light for an extended period of time. 7258 Wsec/cm<sup>2</sup> is the recommended maximum dosage.

### Programming Modes

Programming support is available from Cypress as well as from a number of third-party software vendors. For detailed programming information, including a listing of software packages, please see the PROM Programming Information located at the end of this section. Programming algorithms can be obtained from any Cypress representative.

**Table 1. Programming Electrical Characteristics**

Parameter	Description	Min.	Max.	Unit
V <sub>PP</sub>	Programming Power Supply	12.5	13	V
I <sub>PP</sub>	Programming Supply Current		50	mA
V <sub>IHP</sub>	Programming Input Voltage HIGH	3.0	V <sub>CC</sub>	V
V <sub>ILP</sub>	Programming Input Voltage LOW	-0.5	0.4	V
V <sub>CCP</sub>	Programming V <sub>CC</sub>	6.0	6.5	V

**Table 2. Mode Selection**

Mode	Pin Function <sup>[8]</sup>					
	CE/PGM	OE	V <sub>PP</sub>	A <sub>0</sub>	A <sub>9</sub>	Data
Read	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	A <sub>0</sub>	A <sub>9</sub>	O <sub>7</sub> - O <sub>0</sub>
Output Disable	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IH</sub>	A <sub>0</sub>	A <sub>9</sub>	High Z
Stand-by (CMOS)	V <sub>CC</sub> -0.3V	X	V <sub>IH</sub>	A <sub>0</sub>	A <sub>9</sub>	High Z
Stand-by (TTL)	V <sub>IH</sub>	X	V <sub>IH</sub>	X	X	High Z
Program	V <sub>ILP</sub>	V <sub>IHP</sub>	V <sub>PP</sub>	A <sub>0</sub>	A <sub>9</sub>	D <sub>7</sub> - D <sub>0</sub>
Program Verify	V <sub>ILP</sub>	V <sub>ILP</sub>	V <sub>PP</sub>	A <sub>0</sub>	A <sub>9</sub>	O <sub>7</sub> - O <sub>0</sub>
Program Inhibit	V <sub>IHP</sub>	X	V <sub>PP</sub>	A <sub>0</sub>	A <sub>9</sub>	High Z
Signature Read (MFG)	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IL</sub>	V <sub>HV</sub> <sup>[9]</sup>	34H
Signature Read (DEV)	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IH</sub>	V <sub>HV</sub> <sup>[9]</sup>	Note 10

**Note:**

8. X can be V<sub>IL</sub> or V<sub>IH</sub>.

9. V<sub>HV</sub>=12V±0.5V

10. To be determined.

Ordering Information<sup>[1]</sup>

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
70	CY27C040-70JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C040-70PC	P15	32-Lead (600-Mil) Molded DIP	
	CY27C040-70WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C040-70ZC	Z32	32-Lead Thin Small Outline Package	
90	CY27C040-90JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C040-90PC	P19	32-Lead (600-Mil) Molded DIP	
	CY27C040-90WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C040-90ZC	Z32	32-Lead Thin Small Outline Package	
120	CY27C040-120JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C040-120PC	P19	32-Lead (600-Mil) Molded DIP	
	CY27C040-120WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C040-120ZC	Z32	32-Lead Thin Small Outline Package	
150	CY27C040-150JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C040-150PC	P19	32-Lead (600-Mil) Molded DIP	
	CY27C040-150WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C040-150ZC	Z32	32-Lead Thin Small Outline Package	
200	CY27C040-200JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C040-200PC	P19	32-Lead (600-Mil) Molded DIP	
	CY27C040-200WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C040-200ZC	Z32	32-Lead Thin Small Outline Package	
	CY27C040-200DMB	D20	32-Lead (600-Mil) CerDIP	Military
	CY27C040-200LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
	CY27C040-200QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	
	CY27C040-200WMB	W20	32-Lead (600-Mil) Windowed CerDIP	

## Notes:

- Most of the above products are available in industrial temperature range. Contact a Cypress representative for specifications and product availability.

**MILITARY SPECIFICATIONS  
Group A Subgroup Testing****DC Characteristics**

Parameter	Subgroups
V <sub>OH</sub>	1, 2, 3
V <sub>OL</sub>	1, 2, 3
V <sub>IH</sub>	1, 2, 3
V <sub>IL</sub>	1, 2, 3
I <sub>IX</sub>	1, 2, 3
I <sub>OZ</sub>	1, 2, 3
I <sub>CC</sub>	1, 2, 3
I <sub>SB</sub>	1, 2, 3

**Switching Characteristics**

Parameter	Subgroups
t <sub>AA</sub>	7, 8, 9, 10, 11
t <sub>OE</sub>	7, 8, 9, 10, 11
t <sub>CE</sub>	7, 8, 9, 10, 11

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